

**66348****15 kV HIGH VOLTAGE, 6N134 TYPE HIGH SPEED ISOLATOR**
**OPTOELECTRONIC PRODUCTS  
DIVISION**

04/03/2013

**Features:**

- 2 Mbd Transfer Rate
- 15 kVdc Isolation
- TTL compatible input and output
- Creepage Path: 0.965" min

**Applications:**

- High Voltage Isolation
- Voltage Level Shifting
- Grid Current Modulator
- Switching between power supplies
- Medical systems

**DESCRIPTION**

The **66348** high voltage isolator consists of an 850 nm LED optically coupled to a high speed, high gain inverting detector gate. The isolator output is TTL capable with switching propagation delays of 55 ns typical. The high voltage isolator has an operating free-air temperature range of -40°C to +100°C. The isolator is encased in a high temperature outer PPS housing.

**ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub>=25°C unless otherwise specified)**

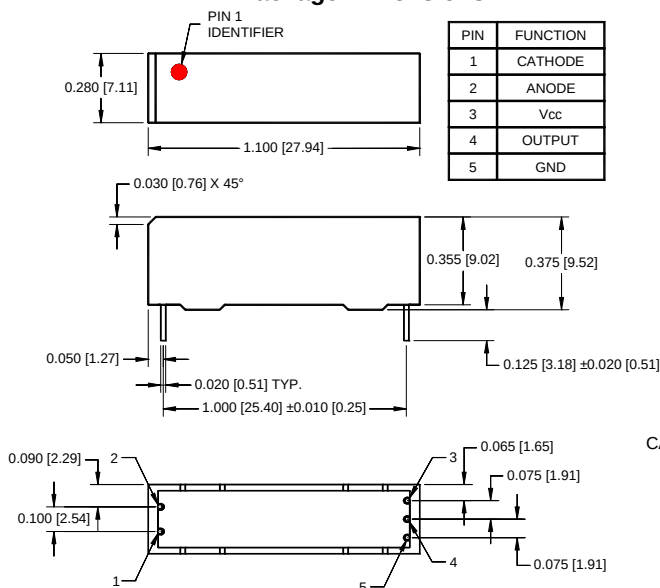
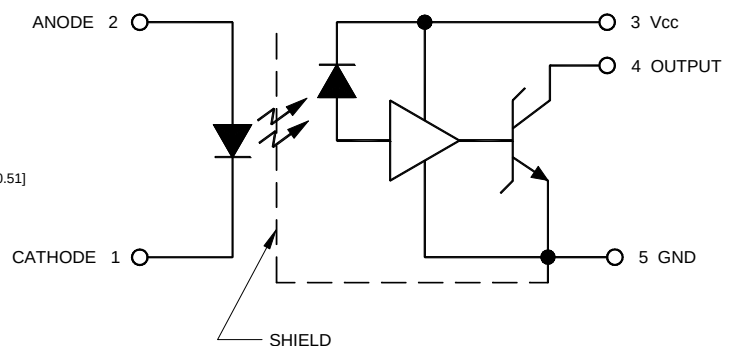
|                                                               |                 |
|---------------------------------------------------------------|-----------------|
| Isolation Voltage (Input to Output) (Note 2)                  | 15 kVdc         |
| Operating Free-Air Temperature Range                          | -40°C to +100°C |
| Storage Temperature                                           | -40°C to +100°C |
| Lead Solder Temperature (10 second, 1.6mm from case) (Note 1) | 260°C           |

**LED:**

|                                                 |        |
|-------------------------------------------------|--------|
| Peak Forward Input Current (2 $\mu$ s duration) | 300 mA |
| Average Forward Input Current                   | 50 mA  |
| Reverse Input Voltage                           | 3.0 V  |
| Input Power Dissipation                         | 100 mW |

**Output IC:**

|                                  |                                    |
|----------------------------------|------------------------------------|
| Supply voltage - V <sub>CC</sub> | -0.5 V to 7.0 V (1 minute maximum) |
| Output Current - I <sub>O</sub>  | 25 mA                              |
| Output Power Dissipation         | 40 mW                              |
| Output Voltage - V <sub>O</sub>  | 7 V                                |

**Package Dimensions****Schematic Diagram**

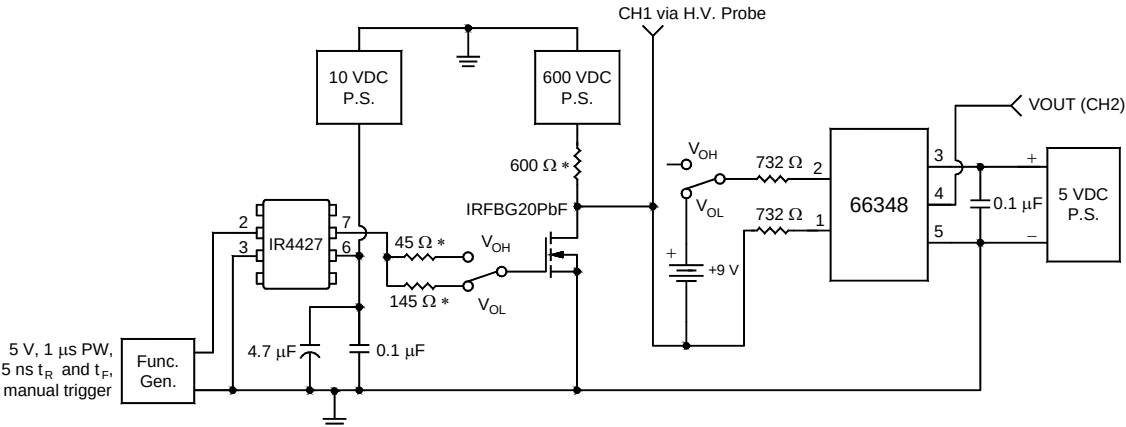
ALL DIMENSIONS ARE IN INCHES [MILLIMETERS] UNLESS OTHERWISE SPECIFIED

**ELECTRICAL CHARACTERISTICS** ( $T_A = 25^\circ\text{C}$  unless otherwise specified)

| PARAMETER                                                         |      | SYMBOL              | MIN    | TYP  | MAX  | UNITS             | TEST CONDITIONS                                                                                                                              | NOTE        |
|-------------------------------------------------------------------|------|---------------------|--------|------|------|-------------------|----------------------------------------------------------------------------------------------------------------------------------------------|-------------|
| <b>Input LED</b>                                                  |      |                     |        |      |      |                   |                                                                                                                                              |             |
| Input Forward Voltage                                             |      | $V_F$               |        | 1.3  | 1.6  | V                 | $I_F = 20\text{ mA}$                                                                                                                         |             |
| Reverse Current                                                   |      | $I_R$               |        |      | 100  | $\mu\text{A}$     | $V_R = 3.0\text{ V}$                                                                                                                         |             |
| <b>Output IC</b>                                                  |      |                     |        |      |      |                   |                                                                                                                                              |             |
| High Level Output Current                                         |      | $I_{OH}$            |        | 0.25 | 15   | $\mu\text{A}$     | $V_{CC} = 5.25\text{ V}$ , $V_{OH} = 5.25\text{ V}$ ,<br>$I_F = 0\text{ mA}$ , $C_L = 0.1\text{ }\mu\text{F}$                                |             |
| Low Level Output Voltage                                          |      | $V_{OL}$            |        | 0.40 | 0.5  | V                 | $V_{CC} = 4.5\text{ V}$ , $I_F = 10\text{ mA}$<br>$I_{OL}$ (Sinking) = 8.0 mA,<br>$C_L = 0.1\text{ }\mu\text{F}$                             |             |
| High Level Supply Current                                         |      | $I_{CCH}$           |        | 2.5  | 7    | mA                | $V_{CC} = 5.25\text{ V}$ , $I_F = 0\text{ mA}$                                                                                               |             |
| Low Level Supply Current                                          |      | $I_{CCL}$           |        | 6    | 10   | mA                | $V_{CC} = 5.25\text{ V}$ , $I_F = 10\text{ mA}$                                                                                              |             |
| <b>Coupled Characteristics (<math>V_{CC} = 5\text{ V}</math>)</b> |      |                     |        |      |      |                   |                                                                                                                                              |             |
| Coupling Capacitance                                              |      | $C_{I-O}$           |        |      | 2.0  | pF                | Input and Output leads shorted                                                                                                               |             |
| Propagation Delay Time To High Output Level                       |      | $t_{PLH}$           |        | 55   | 100  | ns                | $V_{CC} = 5\text{ V}$ , $R_L = 560\text{ }\Omega$ ,<br>$I_F = 10\text{ mA}$ , $C_L = 0.1\text{ }\mu\text{F}$                                 |             |
| Propagation Delay Time To Low Output Level                        |      | $t_{PHL}$           |        | 55   | 200  | ns                | $V_{CC} = 5\text{ V}$ , $R_L = 560\text{ }\Omega$ ,<br>$I_F = 10\text{ mA}$ , $C_L = 0.1\text{ }\mu\text{F}$                                 |             |
| Difference in Propagation Delays                                  |      | $t_{PHL} - t_{PLH}$ |        |      | 100  | ns                |                                                                                                                                              |             |
| Input – Output Isolation Voltage                                  |      | $V_{I-O}$           | 15,000 |      |      | V                 | $I_{I-O} = 25\text{ }\mu\text{A}$                                                                                                            | 2           |
| LED Positive going Threshold Current                              | -001 | $I_{F+}$            | 0.9    |      | 5.0  | mA                | $V_{CC} = 5.0\text{ V}$ , $I_{OL} = 8.0\text{ mA}$<br>$C_L = 0.1\text{ }\mu\text{F}$                                                         |             |
|                                                                   | -002 |                     | 4.0    |      | 15.0 |                   |                                                                                                                                              |             |
| dV/dt Withstand (LED is OFF)                                      |      | $CM_H$              | 5.0    |      |      | kV/ $\mu\text{s}$ | $V_{CC} = 5.0\text{ V}$ , $I_F = 0\text{ mA}$ ,<br>400 V < $V_{CM}$ < 1000 V,<br>$V_{O(MIN)} = 2.0\text{ V}$ , $t = 1\text{ }\mu\text{s}$    | Fig. 1<br>3 |
| dV/dt Withstand (LED is ON)                                       | -001 | $CM_L$              | -5.0   |      |      | kV/ $\mu\text{s}$ | $V_{CC} = 5.0\text{ V}$ , $I_F = 5.0\text{ mA}$ ,<br>400 V < $V_{CM}$ < 1000 V,<br>$V_{O(MAX)} = 0.8\text{ V}$ , $t = 1\text{ }\mu\text{s}$  | Fig. 1<br>3 |
|                                                                   | -002 |                     | -5.0   |      |      |                   | $V_{CC} = 5.0\text{ V}$ , $I_F = 15.0\text{ mA}$ ,<br>400 V < $V_{CM}$ < 1000 V,<br>$V_{O(MAX)} = 0.8\text{ V}$ , $t = 1\text{ }\mu\text{s}$ | Fig. 1<br>3 |

**NOTES:**

- 1) The duration can be extended to 10 seconds maximum when flow soldering. Otherwise 5 seconds with soldering iron.
- 2) Device considered a two terminal device with all Input pins (Anode and Cathode) shorted together and all Output pins ( $V_{CC}$ , GND and Output) shorted together.
- 3) These tests are not performed 100% in production. Tests are run on an evaluation sample of isolators built with each unique sensor wafer lot. Wafer lots that pass evaluation are certified for use in production fabrication of isolators.



\* NOTE: These resistor values are typical and may need adjustment as the FET ages or is replaced.

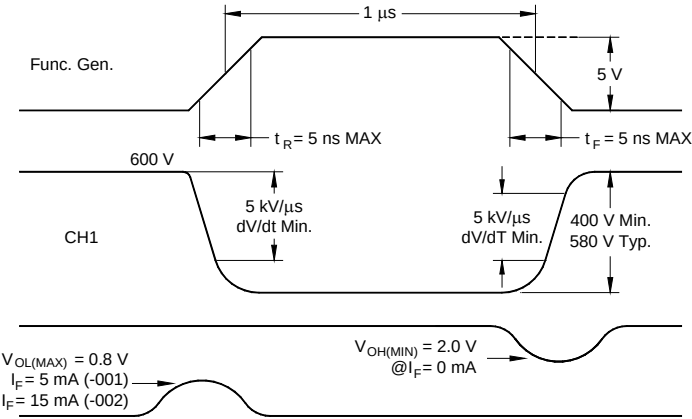


Fig. 1. dV/dt Withstand Test

SELECTION GUIDE

| PART #    | PART DESCRIPTION                                         |
|-----------|----------------------------------------------------------|
| 66348-001 | Commercial, Sensitive                                    |
| 66348-002 | Commercial, Normal                                       |
| 66348-003 | Commercial, Includes solder dipped leads and bubble test |